Diode Semiconductor Device - Page 1 of 1



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| Blass  |  |
|--|--|
| overall Length:  |  |
| .265 inches  |  |
| erminal Length:  |  |
| .000 inches  |  |
| overall Diameter:  |  |
| .105 inches  |  |
| Iounting Method:   |  |
| erminal  |  |
| eatures Provided:  |  |
| lermetically sealed case   |  |
| emiconductor Material:   |  |
| Germanium  |  |
| oltage Rating In Volts Per Characteristic:                         |  |
| 0.0 reverse voltage, peak  |  |
| current Rating Per Characteristic:                                 |  |
| 0.00 milliamperes source cutoff current preset                     |  |
| laximum Operating Tempurature Per Measurement Point:               |  |
| 0.0 degrees celsius junction                                       |  |
| erminal Type And Quantity:   |  |
| uninsulated wire lead  |  |
| pecification Data:   |  |
| 0131-release1257 professional/industrial association specification |  |
| helf Life:   |  |
| l/a  |  |
| Init Of Measure:   |  |
|  |  |
| emilitarization:   |  |
| lo   |  |
| iig:   |  |
| 110a0  |  |